

Plastic Medium Power Silicon NPN Transistor

... designed for use as audio amplifiers and drivers utilizing complementary or quasi complementary circuits.

- DC Current Gain — $h_{FE} = 40$ (Min) @ $I_C = 0.15$ Adc
- BD 165, 169 are complementary with BD 166, 168, 170

MAXIMUM RATINGS

Rating	Symbol	Type	Value	Unit
Collector–Emitter Voltage	V_{CEO}	BD 165	45	
		BD 169	80	
Collector–Base Voltage	V_{CBO}	BD 165	45	Vdc
		BD 169	80	
Emitter–Base Voltage	V_{EBO}		5	Vdc
Collector Current	I_C		1.5	Adc
Base Current	I_B		0.5	Adc
Total Device Dissipation @ $T_A = 25^\circ\text{C}$ Derate above 25°C	P_D		1.25	Watts mW/ $^\circ\text{C}$
			8	
Total Device Dissipation @ $T_C = 25^\circ\text{C}$ Derate above 25°C	P_D		20	Watt mW/ $^\circ\text{C}$
			160	
Operating and Storage Junction Temperature Range	T_J, T_{stg}		–65 to +150	$^\circ\text{C}$

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Case	θ_{JC}	6.25	$^\circ\text{C}/\text{W}$
Thermal Resistance, Junction to Ambient	θ_{JA}	100	$^\circ\text{C}/\text{W}$

ELECTRICAL CHARACTERISTICS ($T_C = 25^\circ\text{C}$ unless otherwise noted)

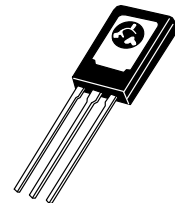
Characteristic	Symbol	Type	Min	Max	Unit
Collector–Emitter Sustaining Voltage* ($I_C = 0.1$ Adc, $I_B = 0$)	BV_{CEO}	BD 165	45	—	Vdc
		BD 169	80	—	
Collector Cutoff Current ($V_{CB} = 45$ Vdc, $I_E = 0$) ($V_{CB} = 80$ Vdc, $I_E = 0$)	I_{CBO}	BD 165	—	0.1	mA dc
		BD 169	—	0.1	
Emitter Cutoff Current ($V_{BE} = 5.0$ Vdc, $I_C = 0$)	I_{EBO}		—	1.0	mA dc
DC current Gain ($I_C = 0.15$ A, $V_{CE} = 2$ V) ($I_C = 0.5$ A, $V_{CE} = 2$ V)	h_{FE}^*		40	—	
			15	—	
Collector–Emitter Saturation Voltage* ($I_C = 0.5$ Adc, $I_B = 0.05$ Adc)	$V_{CE(sat)}^*$		—	0.5	Vdc
Base–Emitter On Voltage* ($I_C = 0.5$ Adc, $V_{CE} = 2.0$ Vdc)	$V_{BE(on)}^*$		—	0.95	Vdc
Current Gain–Bandwidth Product ($I_C = 500$ mA dc, $V_{CE} = 2$ Vdc, $f = 1.0$ MHz)	f_T		6.0	—	MHz

* Pulse Test: Pulse Width ≤ 300 μs , Duty Cycle $\leq 2.0\%$.

REV 7

BD165
BD169

1.5 AMPERE
POWER TRANSISTORS
NPN SILICON
45, 60, 80 VOLTS
20 WATTS



CASE 77–08
TO–225AA TYPE

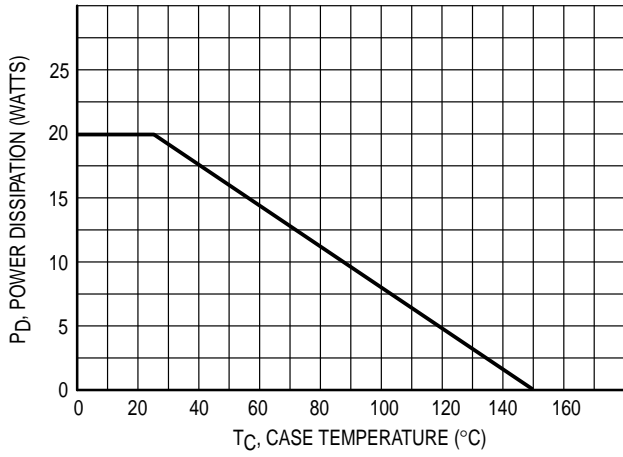


Figure 1. PD – TC Derating Curve

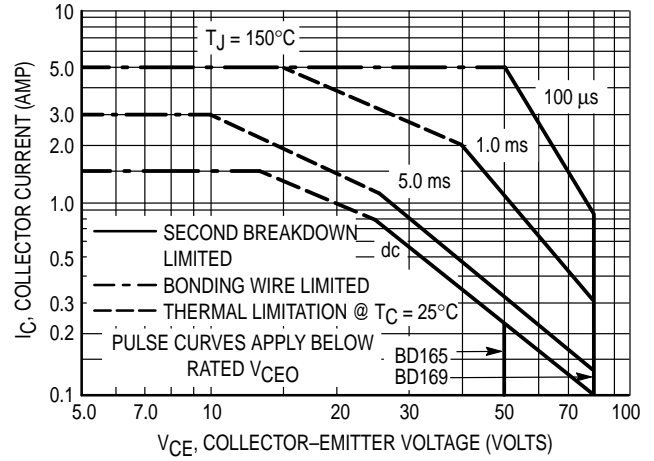


Figure 2. Safe Operating Area (see Note 1)

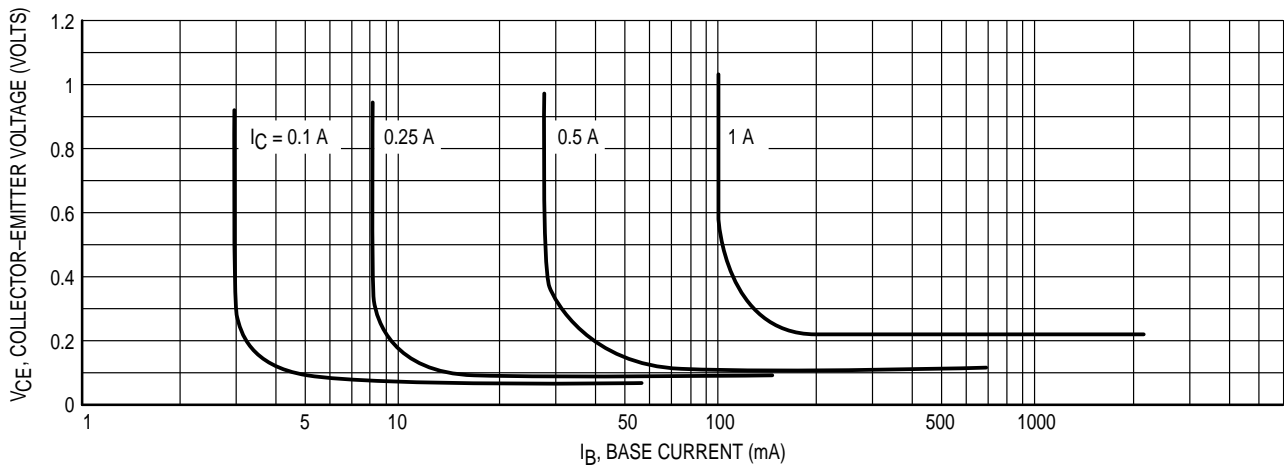


Figure 3. Collector Saturation Region

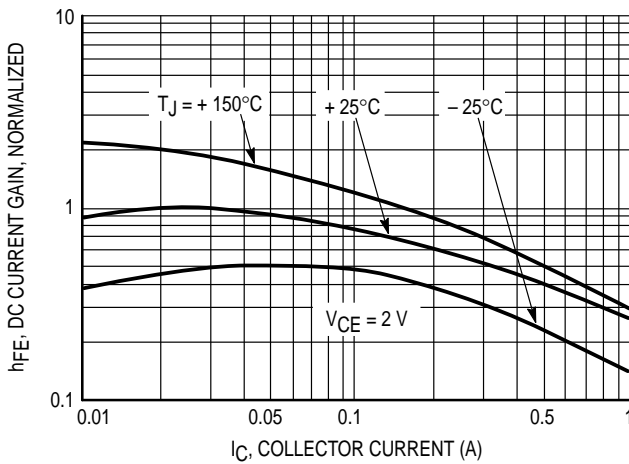


Figure 4. Current Gain

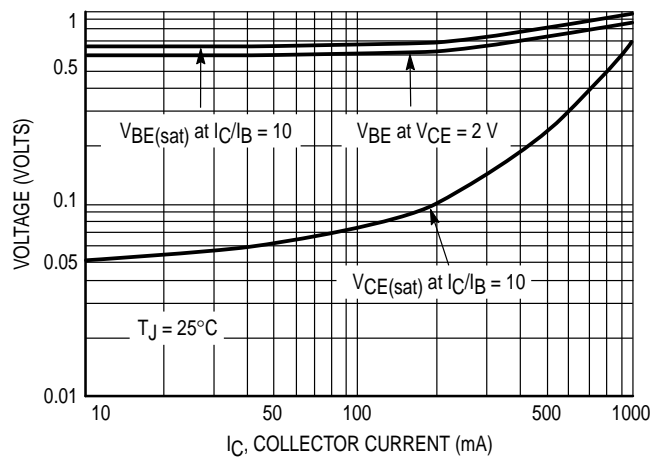


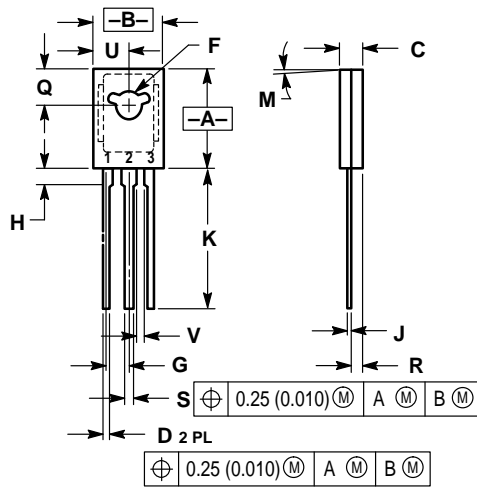
Figure 5. "On" Voltage

Note 1:

There are two limitations on the power handling ability of a transistor; average junction temperature and second breakdown. Safe operating area curves indicate $I_C - V_{CE}$ limits of the transistor that must be observed for reliable operation; i.e., the transistor must not be subjected to greater dissipation than the curves indicate.

The data of Figure 2 is based on $T_{J(pk)} = 150^\circ\text{C}$; T_C is variable depending on conditions. Second breakdown pulse limits are valid for duty cycles to 10% provided $T_{J(pk)} \leq 150^\circ\text{C}$. At high case temperatures, thermal limitations will reduce the power that can be handled to values less than the limitations imposed by second breakdown.

PACKAGE DIMENSIONS




- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.425	0.435	10.80	11.04
B	0.295	0.305	7.50	7.74
C	0.095	0.105	2.42	2.66
D	0.020	0.026	0.51	0.66
F	0.115	0.130	2.93	3.30
G	0.094 BSC		2.39 BSC	
H	0.050	0.095	1.27	2.41
J	0.015	0.025	0.39	0.63
K	0.575	0.655	14.61	16.63
M	5° TYP		5° TYP	
Q	0.148	0.158	3.76	4.01
R	0.045	0.055	1.15	1.39
S	0.025	0.035	0.64	0.88
U	0.145	0.155	3.69	3.93
V	0.040	—	1.02	—

- STYLE 1:
 PIN 1. EMITTER
 2. COLLECTOR
 3. BASE

CASE 77-08
 TO-225AA TYPE
 ISSUE V

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